

Solid State Broadband High Power Amplifier

2194

1000 - 3000 MHz / 250 Watts

The 2194 is suitable for octave bandwidth high power CW, modulated, and pulse applications. This amplifier utilizes high power GaN on SiC devices that provide wide frequency response, high gain, high peak power capability, and low distortions. Exceptional performance, long-term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, EMI/RFI filters, and all qualified components. The amplifier is constructed within one single 3RU drawer including the forced air-cooling. Available operating voltage configuration are single phase 100-240 VAC up to 400HZ and 28 VDC.



SKU#: 2194-001

The amplifier includes a built in control and monitoring system, with protection functions which preserve high availability. Remote management and diagnostics are via an embedded web server allowing network managed site status and control simply by connecting the unit's Ethernet port to a LAN. Using a web browser and the unit's IP address (IPV4) allows ease of access with the benefit of multi-level security. The control system core runs an embedded OS (Linux), has a built-in non-volatile memory for event recording, and factory setup recovery features. The extended memory option allows storage of control parameters and event logs.

Empower RF's ISO9001:2015 Quality Assurance Program assures consistent performance and the highest reliability.

- Solid-state Class AB compact modular design
- Suitable for CW, AM, FM, Pulse and some linear applications (Consult factory for other modulation types)
- Embedded directional coupler Eliminates the need for external component
- 50 ohm input/output impedance
- Built-in Control, Monitoring and Protection functions
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS over temperature conditions (-10 to +40°C)

Parameter	Symbol	Min	Тур	Max	Unit	
Operating Frequency	BW	1000		3000	MHz	
Power Output CW Notes 1,3,4	P _{SAT}	250			Watt	
Power Output @ 1dB Gain Compression Note 2	P _{1dB}	200			Watt	
Power Gain @ 1dB Gain Compression	G _{1dB}	54			dB	
Input Power for Rated P _{SAT}	Pin		0		dBm	
Input Power Range Note 4	P _{IN}	-5.0		+5.0	dBm	
Small Signal Gain Flatness / Leveled ALC	ΔG			±3.5/±1.0	dB	
Gain Adjustment Range @ P _{IN} = -30dBm	VVA	20			dB	
Input Return Loss	S ₁₁			-10	dB	
Noise Figure @ maximum gain	NF			20	dB	
Third Order Intermodulation Distortion 2-Tone @ 48dBm/Tone, 1MHz Spacing	IM3		-28		dBc	
Harmonics @ P _{OUT} = 200W	2 ND		-20	-15	dBc	
Harmonics @ Fout - 200VV	3 RD		-25	-20	UDC	
Spurious Signals	Spur			-60	dBc	
Operating Voltage	V _{AC}	100		240	Volt	
Operating voltage	V_{DC}	24	28	32	VOIL	
Power Consumption @ 250W CW	PD		1100	1500	VA	

Notes: 1. CW measurement performed in MGC Mode (Manual Gain Control)

- P_{1dB} measurements performed with AM 80% depth of modulation, 1 kHz modulation signal.
- 960-1000 MHz Minimum P_{SAT} = 200 Watts. Minimum input power = 0dbm
 The front RF connectors option output power is less by up to 1.00 dB due to added insertion loss of the RF cable routed to the front panel.

MECHANICAL SPECIFICATIONS

Parameter	Value	Unit	
Dimensions W x H x D	17 x 5.25 x 22	lach	
(excludes connectors, handles and brackets)	17 X 5.25 X ZZ	Inch	
Weight	68	Pound	
RF Connectors Input/Output	N-type, Female	RF INPUT / RF OUTPUT	
RF Sample Connectors	SMA, Female	FWD / REV	
Blanking / Gating Input Connector	BNC, Female	Blanking	
Cooling	Built-in forced air-cooling system – front-to-rear	Airflow direction	



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ENVIRONMENTAL CHARACTERISTICS (Qualification Data available for review)

Parameter	Symbol	Min	Тур	Max	Unit
Operating Ambient Temperature *	T _A	-10 *		+40	°C
Non-operating Temperature *	T _{STG}	-20 *		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Shock / Vibration - MIL-STD-810F	SH / VI				
Shock Method 516.5, Vibration Method 514.5	3H / VI				

Note: [*] Consult Empower RF for application conditions below -10°C / -20°C temperatures (Operational / Non-operational).

PROTECTIONS

Parameter	Specification	Unit
Input Overdrive	+10 dBm	Max
VSWR protection	At 3:1 – PA backs-off output power to a safe operating level – no system shutdown, "On Air" time is maximized	1
Thermal – Graceful Degradation	Ambient 40°C	Min
Default Data Recovery	Factory Default Calibration Recovery	

COMMUNICATION INTERFACES

Function	Utility	Connector	
Ethernet	Network management of device / web interface	RJ45	
USB	Mass storage / Expansion Bus	USB 1.x/2.0 compatible	
RS232, default [RS422, factory configurable]	Serial management of device / local operator access	D-Sub 9-position Male	

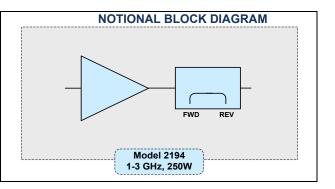
SYSTEM I/O CONNECTOR - 14-Position

Pin#	Description	Specification Specification
1	Reserved	No Connection
2	Reserved	No Connection
3	Summary Fault	Summary Fault: Active TTL Logic Low (≤0.7V), (Internally Pulled-High)
4	Reserved	No Connection
5	Shutdown	Amplifier Disable: TTL Logic Low (≤0.7V), (<i>Internally Pulled-High</i>)
6	Aux P/S Test Point	+12.0V _{DC} ±2.0V (resettable 0.5amp fuse)
7	Main P/S Test Point	+44.0V _{DC} ±4.8V (resettable 0.5amp fuse)
8	GND	Ground
9-11	Open drain control	Site management utility (reserved)
12&13	Digital I/O (configurable)	Site management utility (reserved)
14	GND	Ground

Available Options

2194- <u>XXX</u>
-001 100-240 VAC, 1-phase, 47-63 Hz, Rear RF Connectors
-002 28 VDC, Rear RF Connectors
-003 100-240 VAC, 1-phase, 47-63 Hz, Front RF Connectors Note 4
-004 28 VDC, Front RF Connectors Note 4
Contact us for other available options:
Standard Feature:
-LCD Control, Ethernet & Serial Comm
-Main RF Connectors: Input & Output [N-type Female]
-RF Sample Ports: Forward & Reverse [SMA Female]
-Blanking/Gating Port: BNC Female

-Rack Slides, Handles and Rackmount Bracket

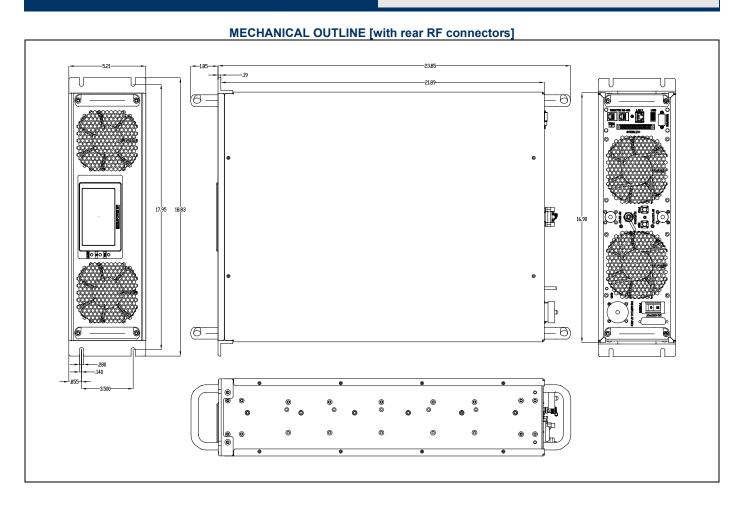




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